THIS DRAWING IS THE PROPERTY OF FAIRCHILD SEMICONDUCTOR CORPORATION. NO USE THEREOF SHALL BE MADE OTHER THAN AS A REFERENCE FOR PROPOSALS AS SUBMITTED			REVISIONS			
TO FARCHILD SEMICONDUCTOR CORPORATION FOR JOBS TO BE EXECUTED IN CONFORMITY WITH SUCH PROPOSALS UNLESS THE CONSENT OF SAID FARCHILD SEMICONDUCTOR COR- PORATION HAS PREVIOUSLY BEEN OBTAINED. NO PART OF THIS DRAWING SHALL BE COPIED OR DUPLICATE DO ITS CONTENTS DISCLOSED. THE INFORMATION CONTAINED			NBR	DESCRIPTION	DATE	BY/APP'D
COPIED OR DUPLICATED OR TIS CONTENTS DISCLOSED. THE INFORMATION CONTAINED ON THIS DRAWING IS CONFIDENTIAL AND PROPRIETARY.		-	1	RELEASED TO DCC	27OCT08	HYANG/ SUZHOU
	Ø b	25.40 MIN 9.50 7.20		RELEASED TO DCC	270CT08	HYANG/ SUZHOU
	Ø 5.60 4.80	, E E E	A) PACK JED B) PLAS D) ALL [E) Øb DI OF OF	MENSION REPR TION AD = 1.20	D REFERENCE: ATION AD. ODY. E IN MILLIMETE RESENT LIKE BE MIN TO 1.30MAX MIN TO 1.07MAX	LOW:
			DRAWN: BOB CHECKED: HE APPROVED: BY APPROVED:	DVALS DATE OY MALDO 27OCT08 ENRY YANG Y HUANG ARD ALLEN	AXIAL LEADED, J OPTION A SCALE 1:1 N/A DRAWING NU FORMERLY: N/A	ETOR™ IEDEC DO201 D & AE